

Product Description

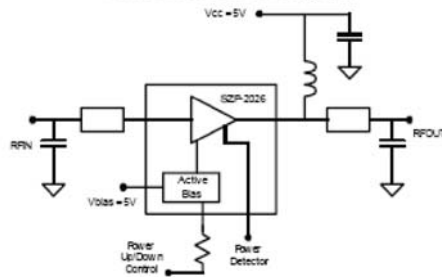
RFMD's SZP-2026Z is a high linearity single stage class AB Heterojunction Bipolar Transistor (HBT) amplifier housed in a proprietary surface-mountable plastic encapsulated package. This HBT amplifier is made with InGaP on GaAs device technology and fabricated with MOCVD for an ideal combination of low cost and high reliability. This product is specifically designed as a flexible final or driver stage for 802.16 and 802.11 equipment in the 2.2GHz to 2.7GHz bands. It can run from a 3V to 6V supply. It is prematched to ~5Ω on the input for broadband performance and ease of matching at the board level. It features an output power detector, on/off power control, ESD protection, excellent overall robustness and a proprietary hand reworkable and thermally enhanced SOF-26 package. This product features a RoHS Compliant and Green package with matte tin finish, designated by the 'Z' suffix.

Optimum Technology Matching® Applied

- GaAs HBT
- GaAs MESFET
- InGaP HBT
- SiGe BiCMOS
- Si BiCMOS
- SiGe HBT
- GaAs pHEMT
- Si CMOS
- Si BJT
- GaN HEMT
- InP HBT
- RF MEMS
- LDMOS

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Functional Block Diagram



Features

- P_{1dB} = 33.5dBm at 5V, 2.4GHz
- 802.11g 54 Mb/s Class AB Performance
- P_{OUT} = 26 dBm at 2.5% EVM, V_{CC} 5V
- P_{OUT} = 27 dBm at 2.5% EVM, V_{CC} 6V
- On-Chip Output Power Detector
- Input Prematched to ~5Ω
- Proprietary Low Thermal Resistance Package
- Hand Solderable and Easy Rework
- Power Up/Down control < 1μs

Applications

- 802.16 WiMAX Driver or Output Stage
- 2.4GHz 802.11 WiFi and ISM Applications

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Frequency of Operation,	2200		2700	MHz	
Output Power at 1dB Compression	31.5	33.0		dBm	2.7GHz
Small Signal Gain	11.3	12.8		dB	2.7GHz
EVM		2.5		%	2.7GHz, 802.11g 54Mb/s at P _{OUT} =26dBm
Third Order Suppression		-45.0	-42.0	dBc	2.7GHz, P _{OUT} =23dBm per tone
Noise Figure		4.3		dB	2.7GHz
Worst Case Input Return Loss	8.0	12.0		dB	2.5GHz to 2.7GHz
Worst Case Output Return Loss	8.0	12.0		dB	2.5GHz to 2.7GHz
Output Voltage Range		0.85 to 1.4		V	P _{OUT} = 10dBm to 33dBm
Quiescent Current	395	445	495	mA	V _{CC} = 5V
Power Up Control Current		2.1		mA	V _{PC} = 5V
VCC Leakage Current			10	μA	V _{CC} = 5V, V _{PC} = 0V
Thermal Resistance		12.0		°C/W	junction - lead

Test Conditions: Z₀ = 50Ω, V_{CC} = 5V, I_Q = 445mA, T_{BP} = 30°C

Absolute Maximum Ratings

Parameter	Rating	Unit
VC1 Collector Bias Current (I_{VC1})	1500	mA
**Device Voltage (V_D)	7.0	V
Power Dissipation	6	W
*Max RF output Power for 50Ω continuous long term operation	30	dBm
Max RF Input Power for 50W output load	28	dBm
Max RF Input Power for 10:1 VSWR output load	23	dBm
Junction Temp (T_J)	+150	°C
Operating Lead Temperature (T_L)	-40 to +85	°C
Storage Temperature Range	-40 to +150	°C
ESD Rating - Human Body Model	1000	V



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

The information in this publication is believed to be accurate and reliable. However, no responsibility is assumed by RF Micro Devices, Inc. ("RFMD") for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. No license is granted by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice.

*Note: With specified application circuit

**Note: No RF Drive

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression:

$$I_D V_D < (T_J - T_L) / R_{TH, j}$$

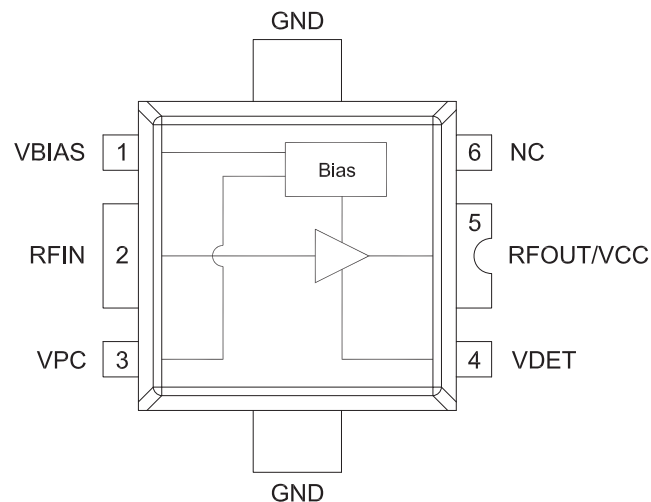
Typical Performance 2.4GHz to 2.5GHz and 2.5GHz to 2.7GHz App Circuits ($V_{CC}=5V$, 802.11g 54Mb/s 64QAM)

Parameter	Unit	*2.4 GHz	*2.5 GHz	**2.6 GHz	**2.7 GHz
Gain	dB	13.3	13.0	12.8	12.7
P1dB	dBm	33.5	33.3	33.6	33.3
P_{OUT} at 2.5% EVM	dBm	26.0	26.0	26.2	26.0
Current at P_{OUT} at 2.5% EVM	mA	550	545	570	570
Input Return Loss	dB	16.0	12.0	17.0	13.0
Output Return Loss	dB	16.0	16.0	17.0	15.0

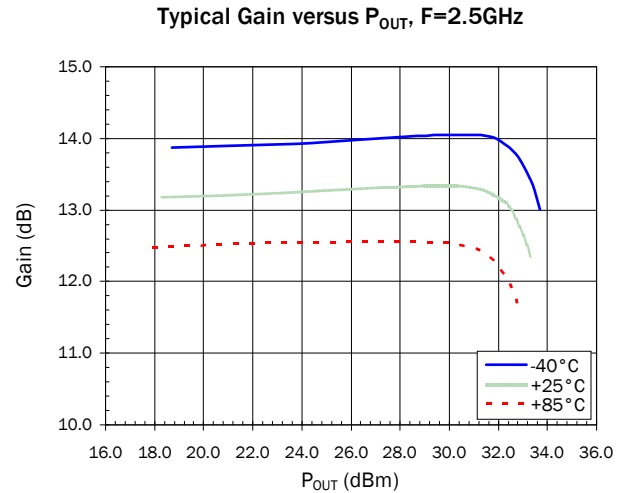
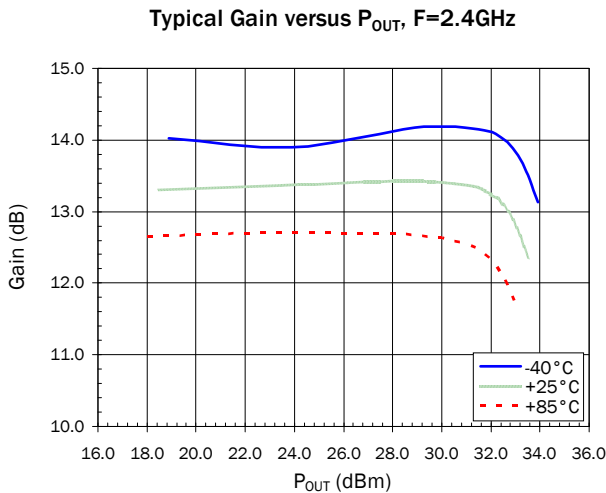
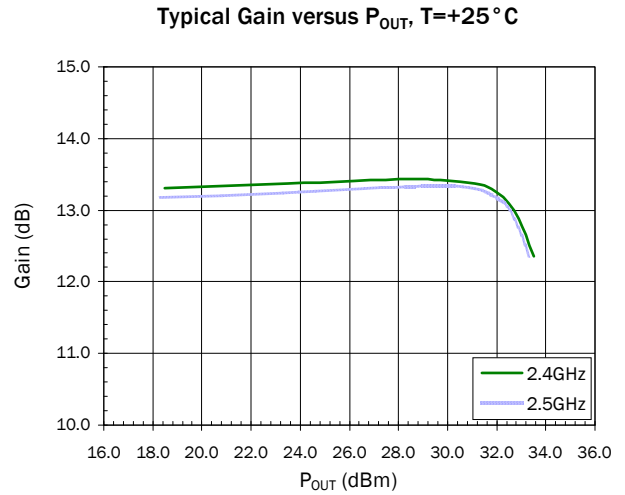
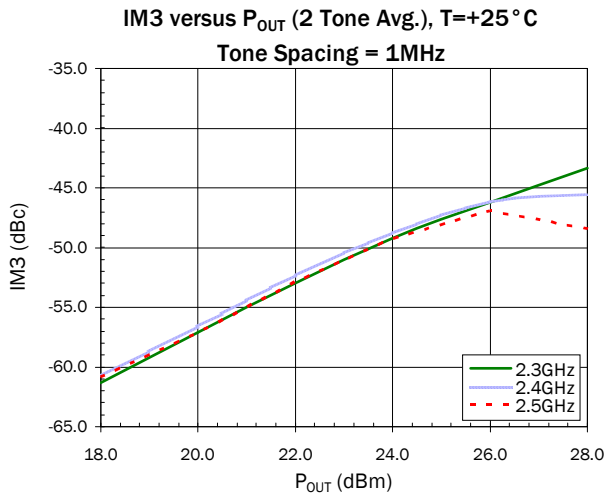
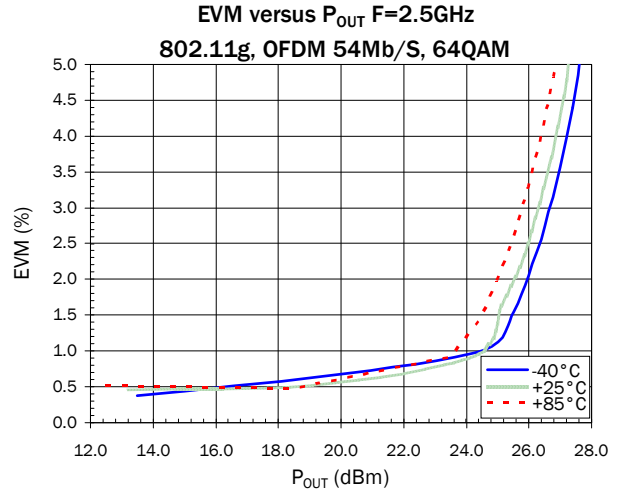
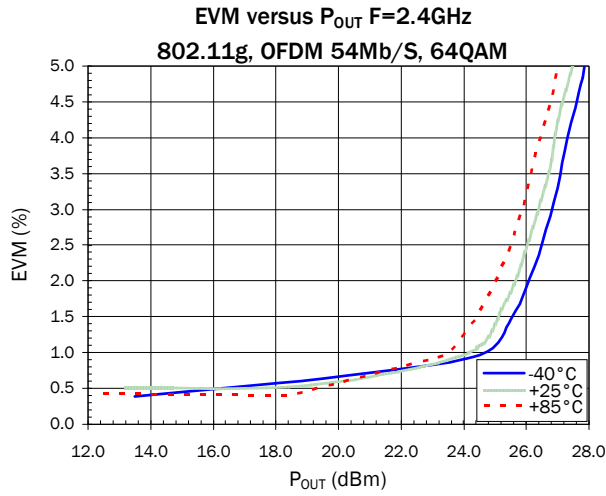
*Measured with 2.4GHz to 2.5GHz Applications Circuit

**Measured with 2.5GHz to 2.7GHz Applications Circuit

Simplified Device Schematic

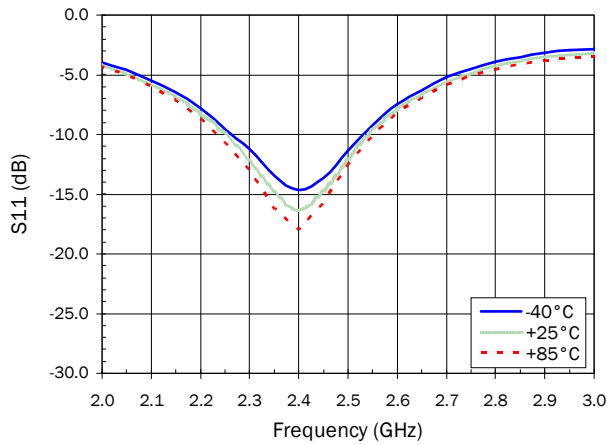


Measured 2.4GHz to 2.5GHz Application Circuit Data ($V_{CC}=V_{PC}=5.0V$ $I_Q=445mA$, $T=25^\circ C$)

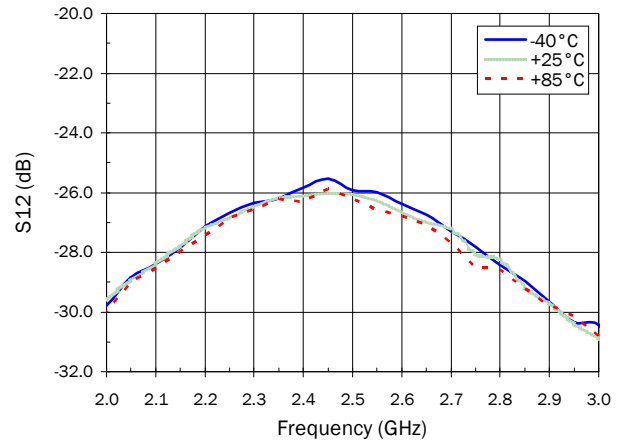


Measured 2.4GHz to 2.5GHz Application Circuit Data ($V_{CC}=V_{PC}=5.0V$ $I_Q=445mA$, $T=25^\circ C$)

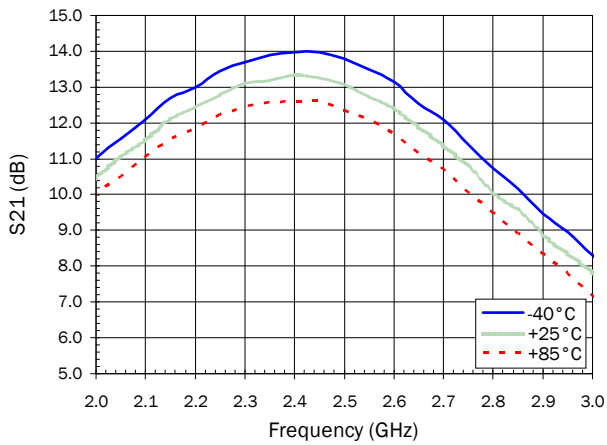
Narrowband S11 - Input Return Loss



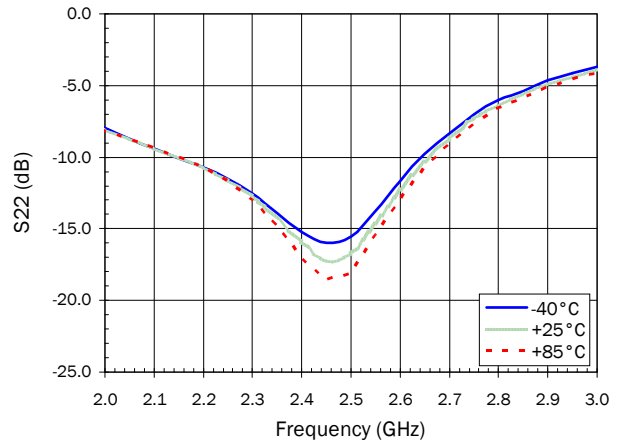
Narrowband S12 - Reverse Isolation



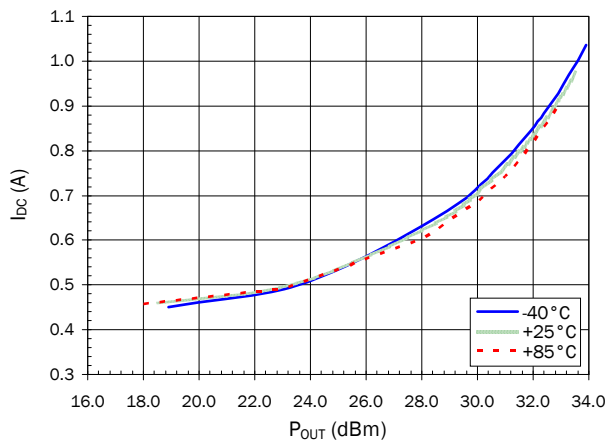
Narrowband S21 - Forward Gain



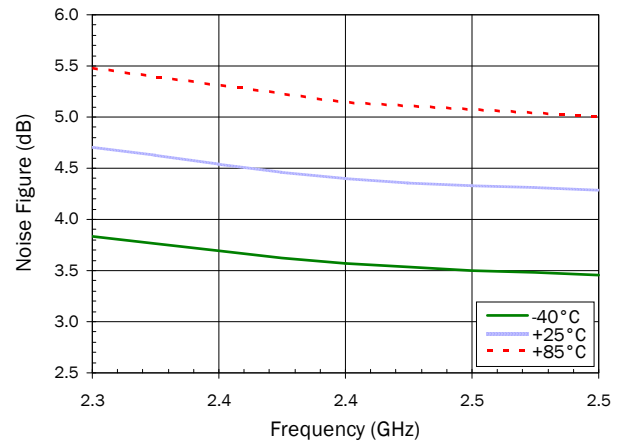
Narrowband S22 - Output Return Loss



DC Supply Current versus P_{OUT} , $F=2.4GHz$

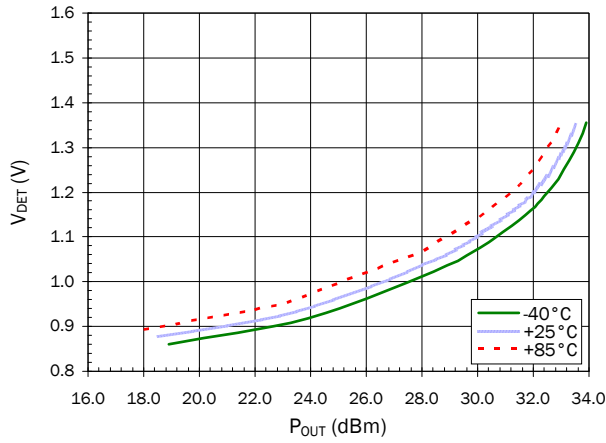


Noise Figure versus Frequency, O.T.

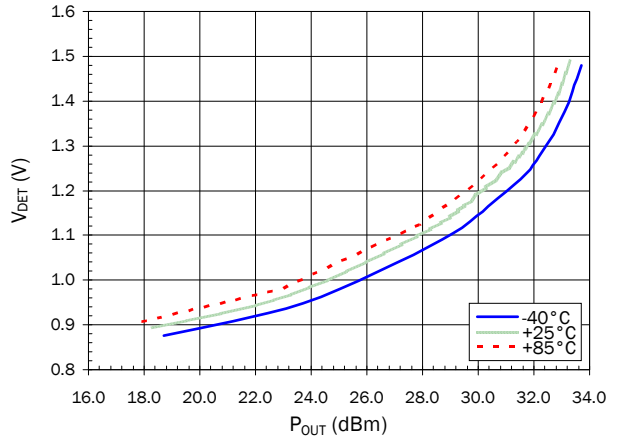


Measured 2.4GHz to 2.5GHz Application Circuit Data ($V_{CC}=V_{PC}=5.0V$ $I_Q=445mA$, $T=25^\circ C$)

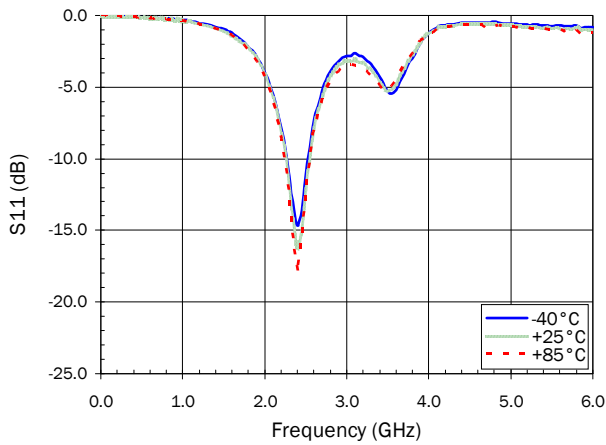
RF Power Detector (V_{DET}) versus P_{OUT} , F=2.4GHz



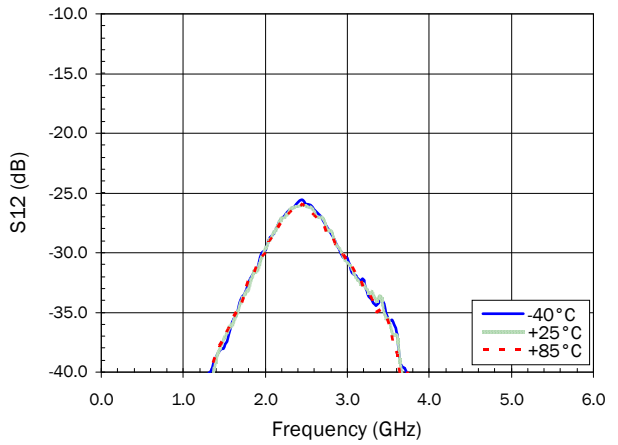
RF Power Detector (V_{DET}) versus P_{OUT} , F=2.5GHz



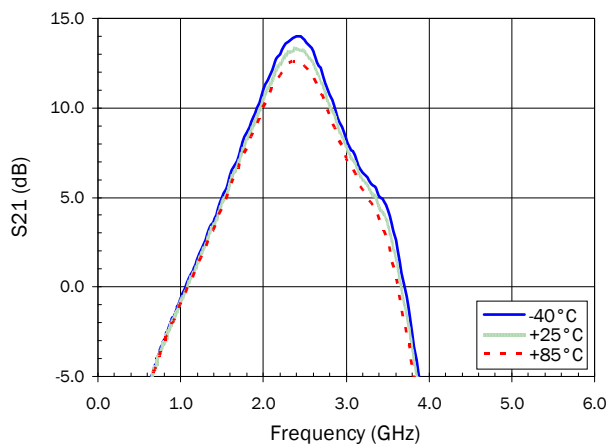
Broadband S11 - Input Return Loss



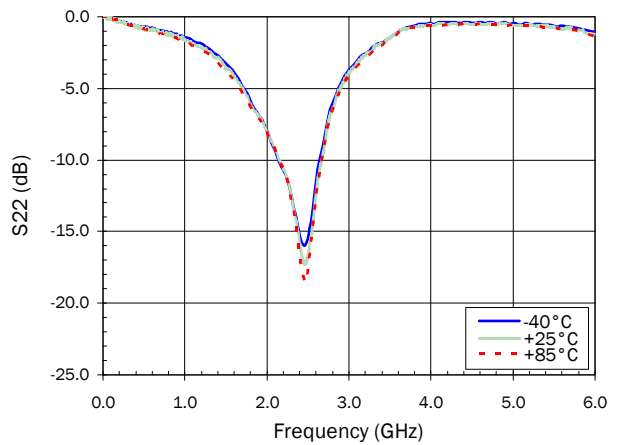
Broadband S12 - Reverse Isolation



Broadband S21 - Forward Gain

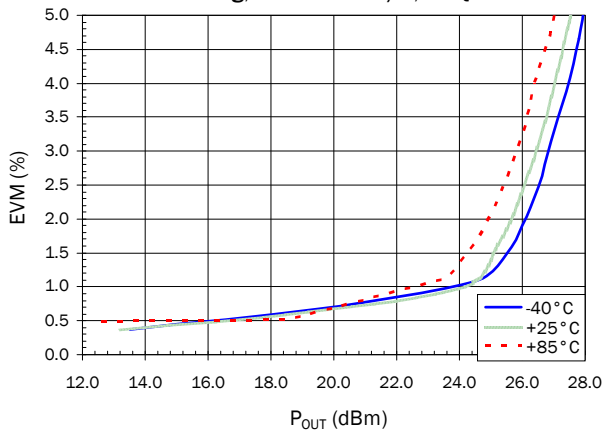


Broadband S22 - Output Return Loss

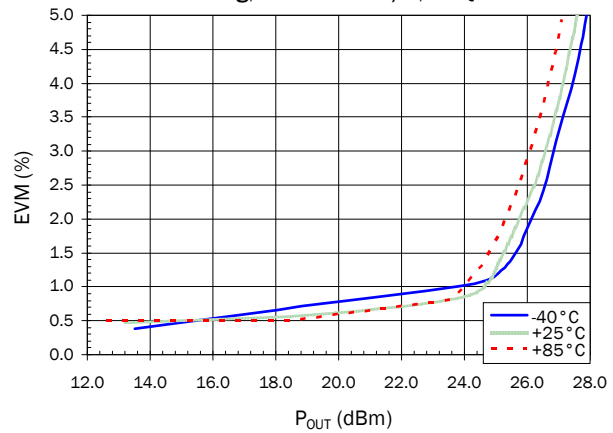


Measured 2.5GHz to 2.7GHz Application Circuit Data ($V_{CC}=V_{PC}=5.0V$ $I_Q=445mA$, $T=25^\circ C$)

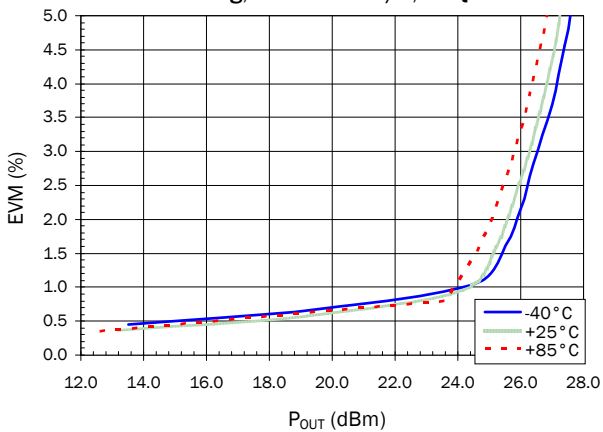
EVM versus P_{OUT} F=2.5GHz
802.11g, OFDM 54Mb/S, 64QAM



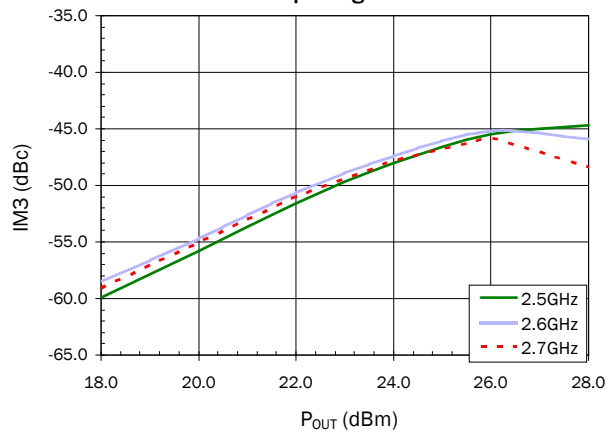
EVM versus P_{OUT} F=2.6GHz
802.11g, OFDM 54Mb/S, 64QAM



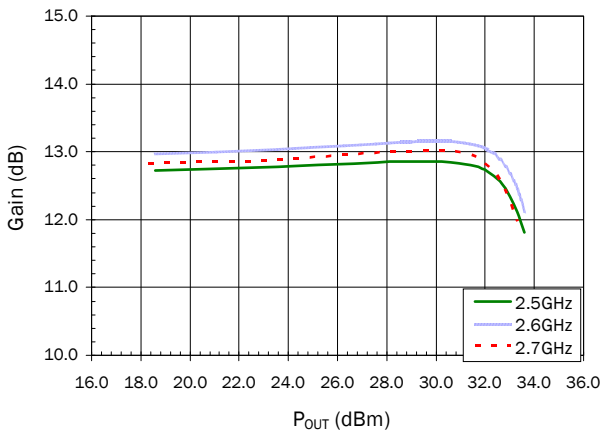
EVM versus P_{OUT} F=2.7GHz
802.11g, OFDM 54Mb/S, 64QAM



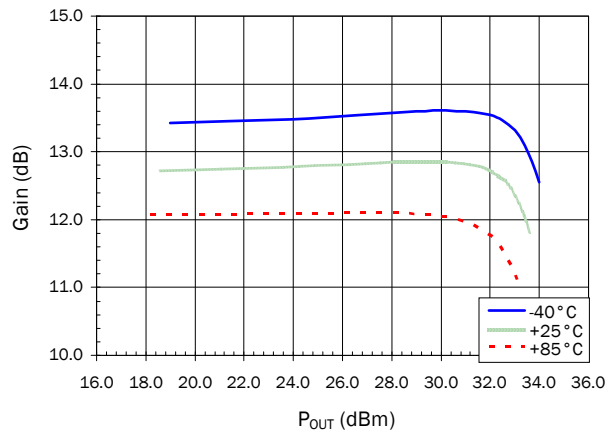
IM3 versus P_{OUT} (2 Tone Avg.), T=+25°C
Tone Spacing=1MHz



Typical Gain versus P_{OUT} , T=+25°C

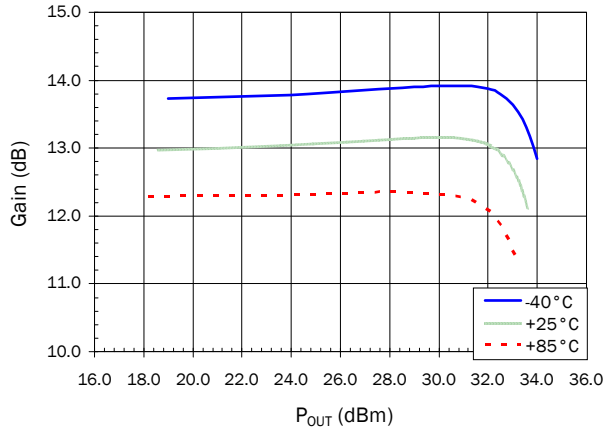


Typical Gain versus P_{OUT} , F=2.5GHz

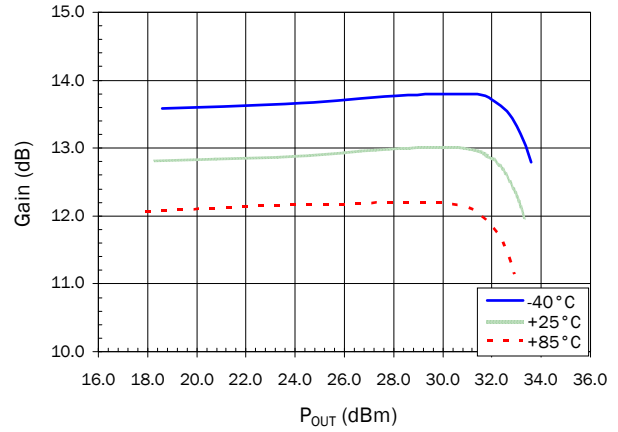


Measured 2.5GHz to 2.7GHz Application Circuit Data ($V_{CC}=V_{PC}=5.0V$ $I_Q=445mA$, $T=25^\circ C$)

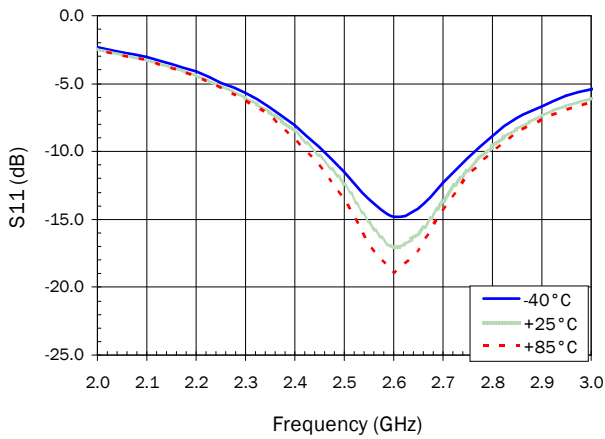
Typical Gain versus P_{OUT} , $F=2.6GHz$



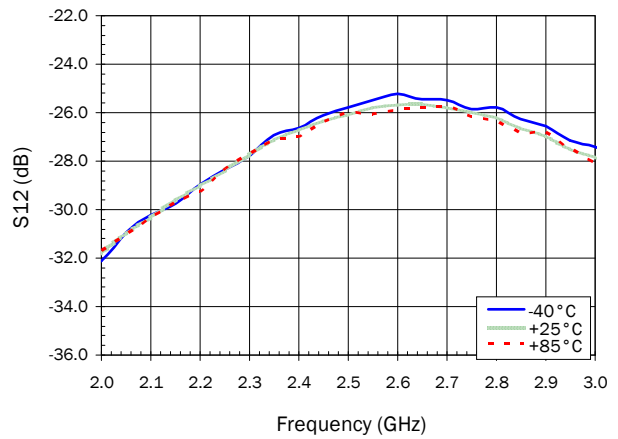
Typical Gain versus P_{OUT} , $F=2.7GHz$



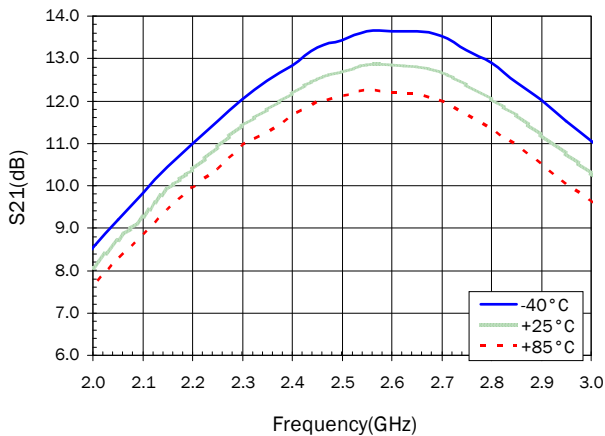
Narrowband S11 - Input Return Loss



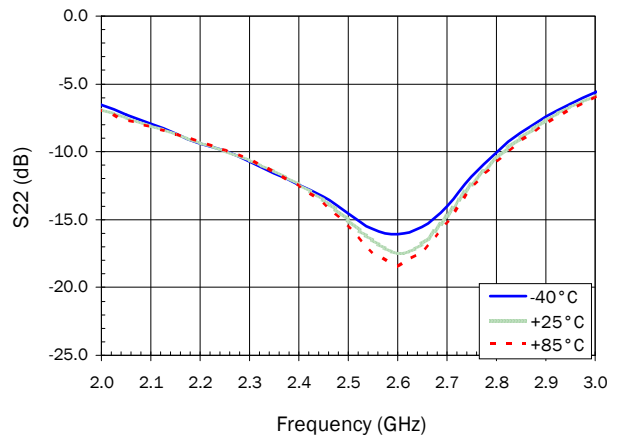
Narrowband S12 - Reverse Isolation



Narrowband S21 - Forward Gain

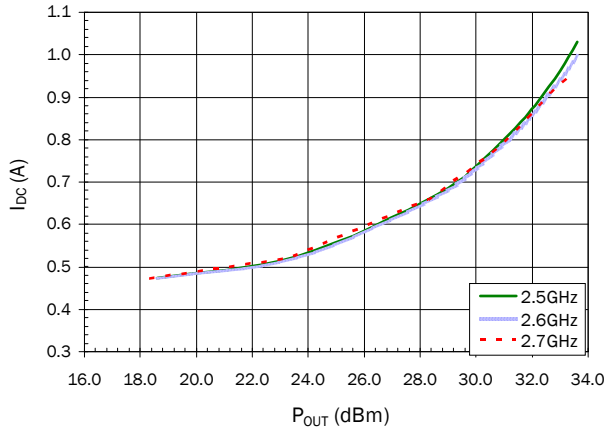


Narrowband S22 - Output Return Loss

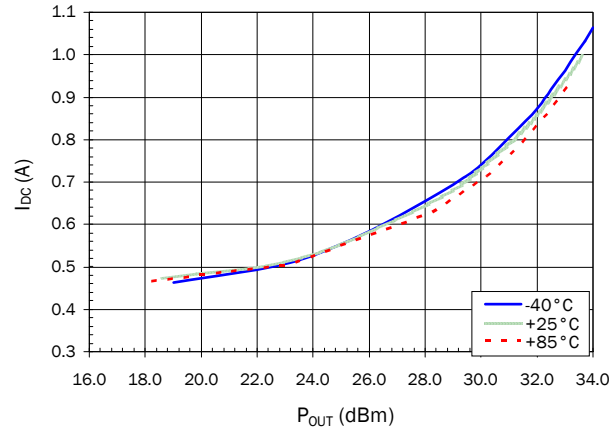


Measured 2.5GHz to 2.7GHz Application Circuit Data ($V_{CC}=V_{PC}=5.0V$ $I_Q=445mA$, $T=25^\circ C$)

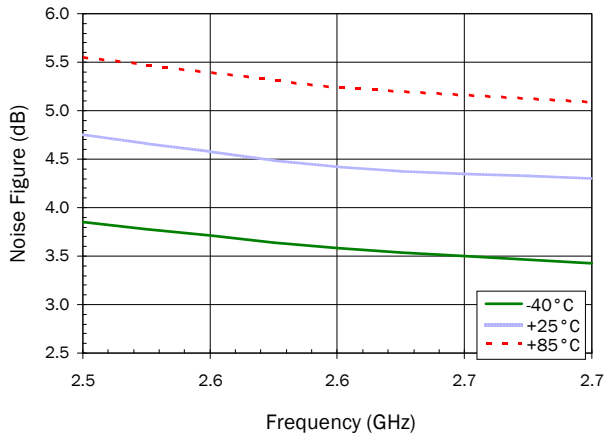
DC Supply Current versus P_{OUT} , $T=+25^\circ C$



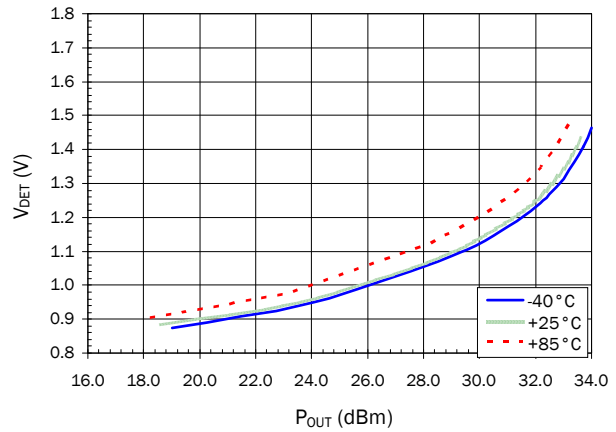
DC Supply Current versus P_{OUT} , $F=2.6GHz$



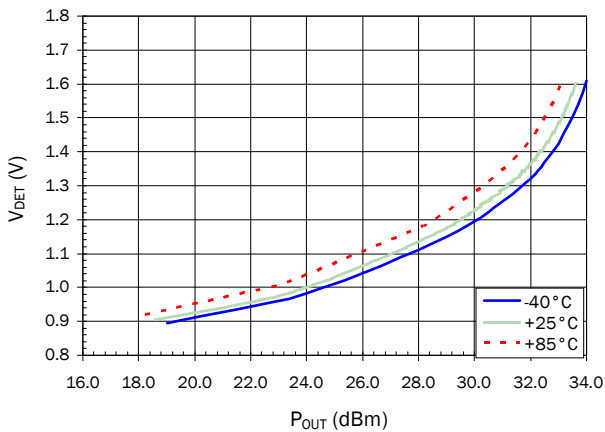
Noise Figure versus Frequency, O.T.



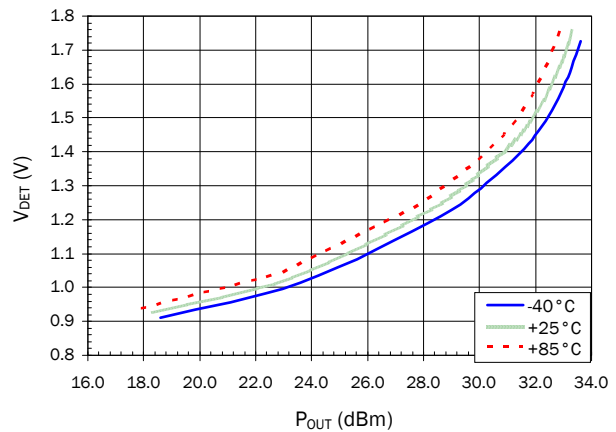
RF Power Detector (V_{DET}) versus P_{OUT} , $F=2.5GHz$



RF Power Detector (V_{DET}) versus P_{OUT} , $F=2.6GHz$

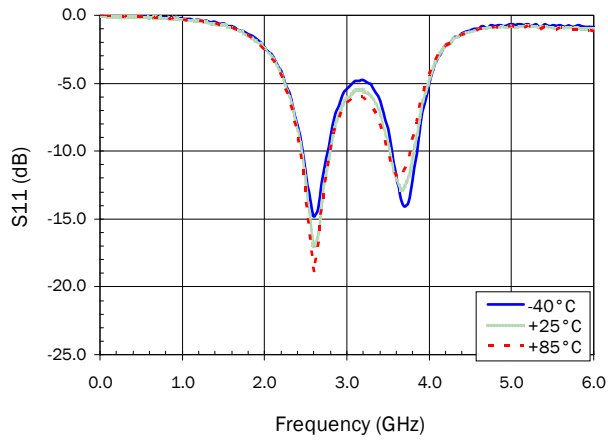


RF Power Detector (V_{DET}) versus P_{OUT} , $F=2.7GHz$

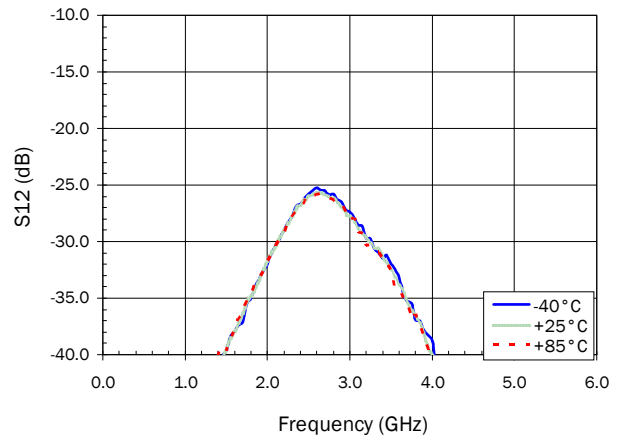


Measured 2.5GHz to 2.7GHz Application Circuit Data ($V_{CC}=V_{PC}=5.0V$ $I_Q=445mA$, $T=25^\circ C$)

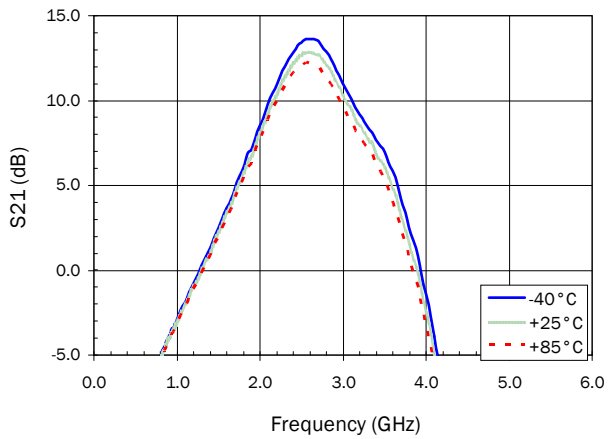
Broadband S11 - Input Return Loss



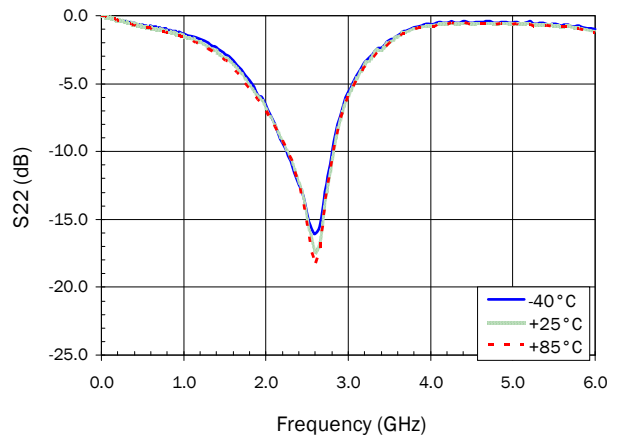
Broadband S12 - Reverse Isolation



Broadband S21 - Forward Gain



Broadband S22 - Output Return Loss

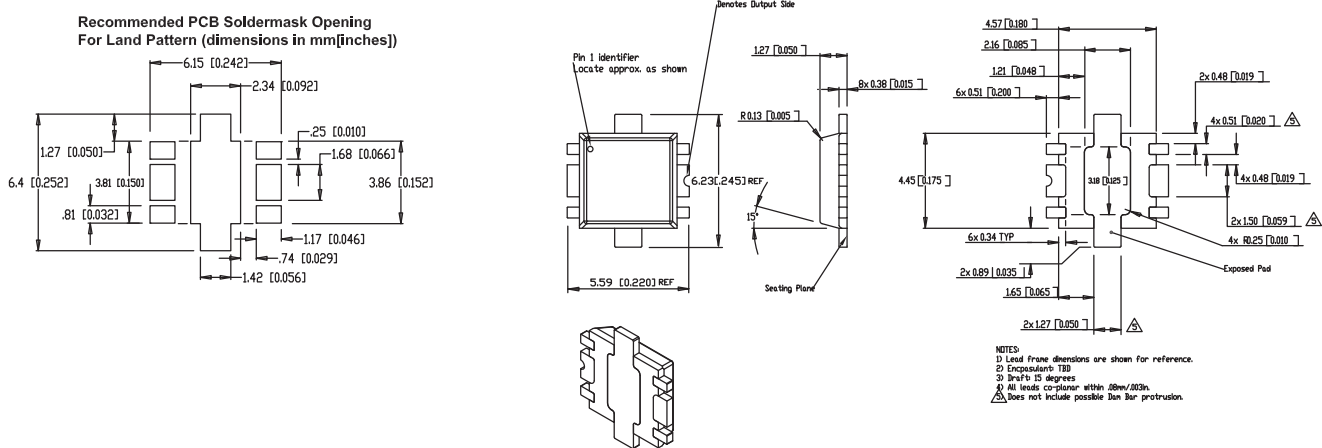


Pin	Function	Description
1	VBIAS	This is the supply voltage for the active bias circuit.
2	RF IN	This is the RF input pin and has a DC voltage present. An external DC block is required.
3	VPC	Power up/down control pin. The voltage on this pin should never exceed the voltage on pin 1 by more than 0.5V unless the supply current from pin 3 is limited < 10mA.
4	VDET	This is the output port for the power detector. It samples the power at the input of the amplifier.
5	RF OUT/VCC	This is the RF output pin and DC connection to the collector.
6	NC	This pin is not connected internal to the package. Buss it to pin 5 as shown on the app circuit to achieve the specified performance.
GND	GND	These pins are DC connected to the backside paddle. They provide good thermal connection to the backside paddle for hand soldering and rework. Many thermal and electrical GND vias are recommended as shown in the landing pattern.

Package Drawing

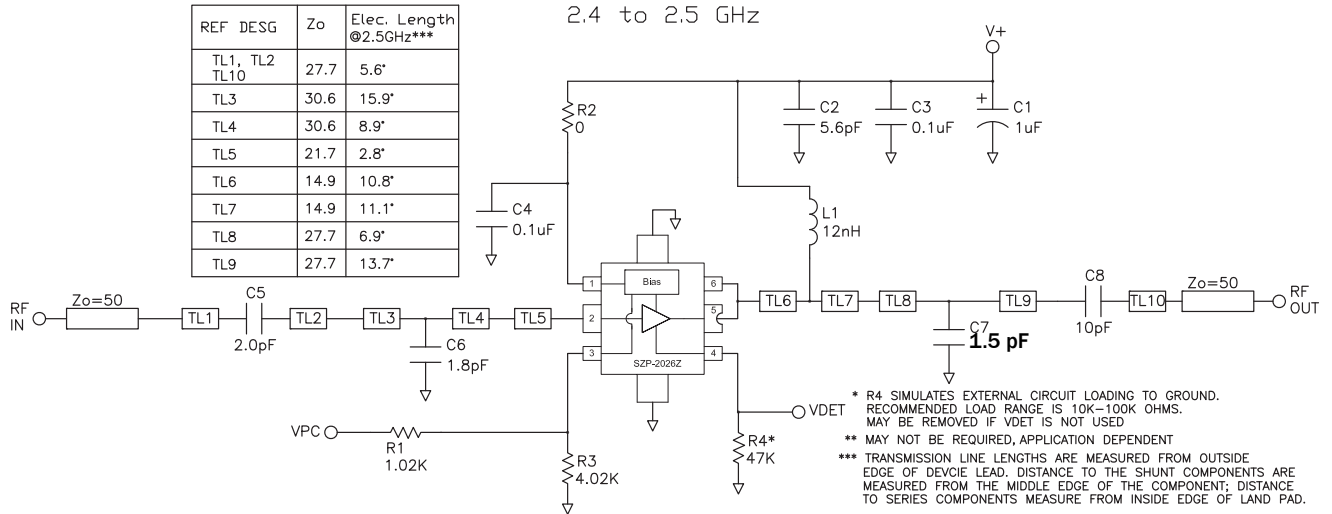
Dimensions in millimeters (inches)

Refer to drawing posted at www.rfmd.com for tolerances.



Application Schematic (2.4 GHz to 2.5 GHz)

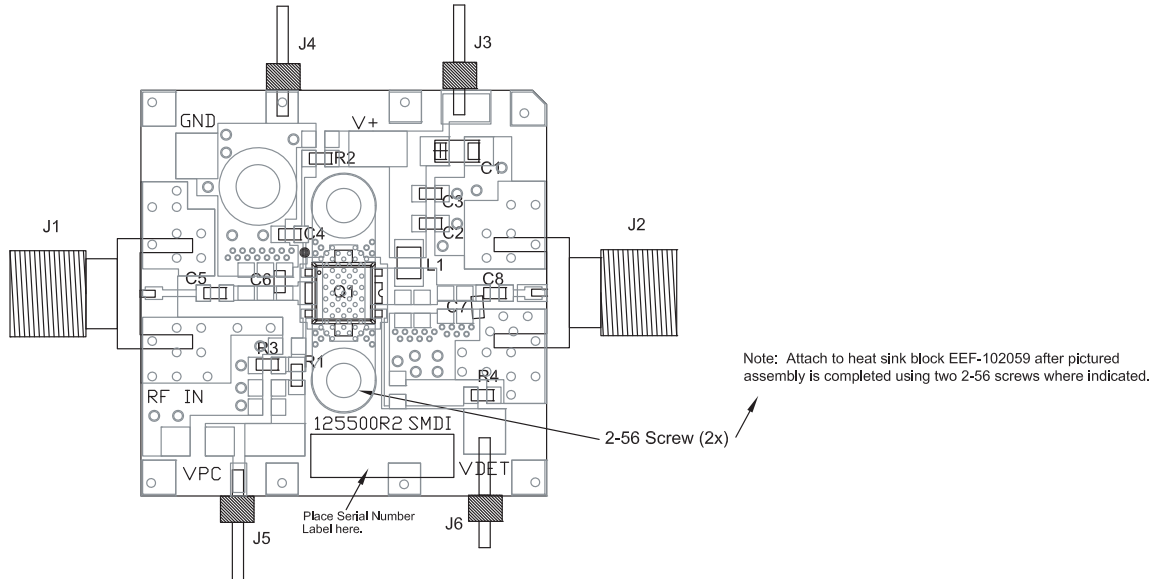
For $V+ = V_{CC} = V_{PC} = 5.0V$



Evaluation Board Layout (2.4GHz to 2.5GHz)

For $V_+ = V_{CC} = V_{PC} = 5.0V$

Board Material GETEK, 10mil thick, Dk=3.9, 2oz. copper



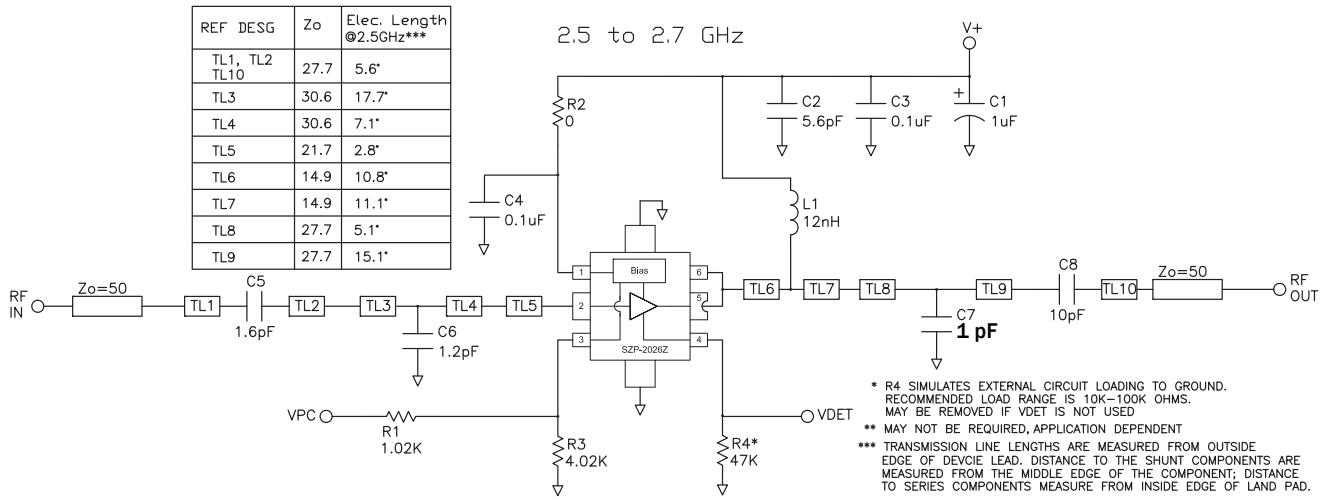
PCB Notes: Do not use less than the recommended number of via holes under the device ground paddle. RF layers thicker than .020 inches (0.5mm) not recommended.

Bill of Materials (2.4GHz to 2.5GHz)

DESG	Description	Notes
Q1	SZP-2026Z	SOF-26
R1	1.02K, Ω , 0603 1%	0402 may be used
R2	0 Ω , 0603	0402 may be used
R3	4.02K, Ω , 0603 1%	0402 may be used
R4	47K, Ω , 0603	0402 may be used
C1	1uF 16V MLCC CAP	Tantalum ok for EVM performance. Use MLCC type for best IM3 levels.
C2	5.6pF CAP, 0603	NPO ROHM MCH185A5R6DK or equiv.
C3, 4	0.1uF CAP, 0603	X7R 0402 ok, ROHM MCH182CN104K or equiv.
C5	2.0pF CAP, 0603	NPO, low ESR ATC 600S2R0JW250 or equiv.
C6	1.8pF CAP, 0603	NPO, low ESR ATC 600S1R8CW250 or equiv.
C7	1.5pF CAP, 0603	NPO, low ESR ATC 600S1R5CW250 or equiv.
C8	10pF CAP, 0603	NPO, low EST ATC 600S100JW250 or equiv.
L1	12nH IND, 0805	Coilcraft 0805HQ-12NXJBB.

Application Schematic (2.5GHz to 2.7GHz)

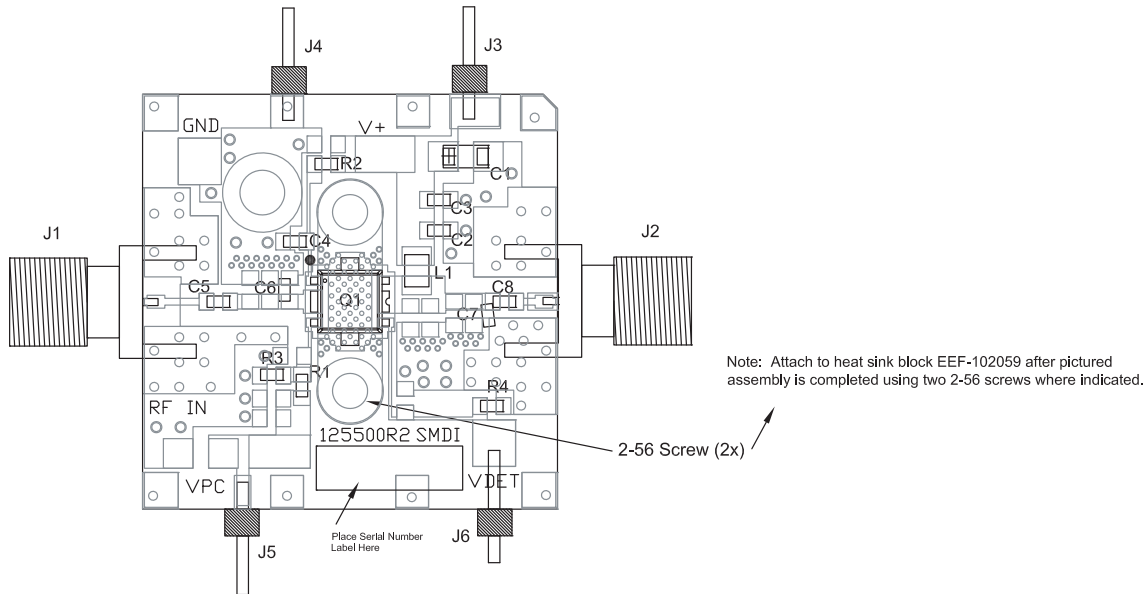
For $V_+ = V_{CC} = V_{PC} = 5.0V$



Evaluation Board Layout and Bill of Materials (2.5GHz to 2.7GHz)

For $V_+ = V_{CC} = V_{PC} = 5.0V$

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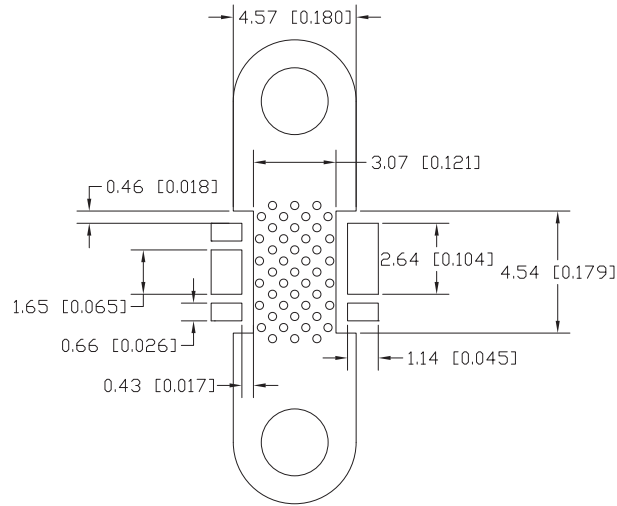
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Bill of Materials (2.5GHz to 2.7GHz)

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R2	0 Ω , 0603	0402 may be used
R3	4.02K, Ω , 0603 1%	0402 may be used
R4	47K, Ω , 0603	0402 may be used
C1	1uF 16V MLCC CAP	Tantalum ok for EVM performance. Use MLCC type for best IM3 levels.
C2	5.6pF CAP, 0603	NPO ROHM MCH185A5R6DK or equiv.
C3, 4	0.1uF CAP, 0603	X7R 0402 ok, ROHM MCH182CN104K or equiv.
C5	1.6pF CAP, 0603	NPO, low ESR ATC 600S1R6JW250 or equiv.
C6	1.2pF CAP, 0603	NPO, low ESR ATC 600S1R2CW250 or equiv.
C7	1.0pF CAP, 0603	ROHM MCH185A1R0DK or equiv. NPO 0402 ok.
C8	10pF CAP, 0603	NPO, low EST ATC 600S100JW250 or equiv.
L1	12nH IND, 0805	Coilcraft 0805HQ-12NXJBB.

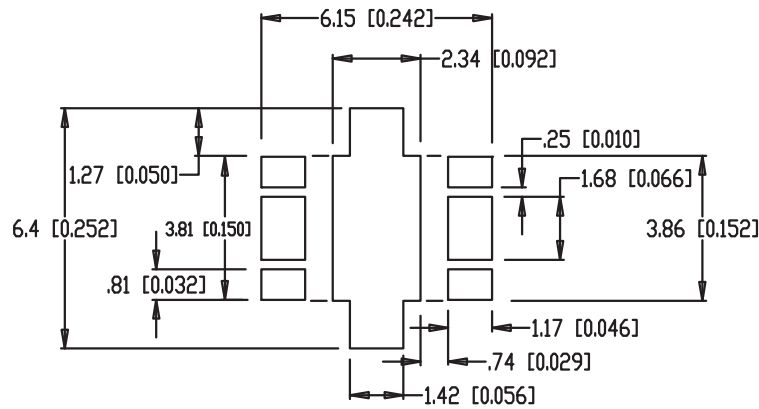
Recommended Metal Land Pattern

Dimensions in millimeters (inches)



Recommended Soldermask Pattern

Dimensions in millimeters (inches)



Part Symbolization

The part will be symbolized with "SZP-2026Z" to designate it as a RoHS green compliant product. Marking designator will be on the top surface of the package.

Ordering Information

Ordering Code	Description
SZP2026ZSQ	Standard 25 piece bag
SZP2026ZSR	Standard 100 piece reel
SZP2026Z	Standard 1000 piece reel
SZP2026Z-EVB1	Evaluation Board 2.4GHz to 2.5GHz Tune
SZP2026Z-EVB2	Evaluation Board 2.5GHz to 2.7 GHz Tune